## **Excellent Integrated System Limited**

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<u>Fairchild Semiconductor</u> <u>KST5551MTF</u>

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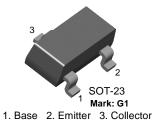




## KST5551

## **Amplifier Transistor**

- Collector-Emitter Voltage: V<sub>CEO</sub>=160V
   Collector Power Dissipation: P<sub>C</sub> (max)=350mW



## **NPN Epitaxial Silicon Transistor**

### **Absolute Maximum Ratings** T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	180	V
V <sub>CEO</sub>	Collector-Emitter Voltage	160	V
V <sub>EBO</sub>	Emitter-Base Voltage	6	V
I <sub>C</sub>	Collector Current	600	mA
P <sub>C</sub>	Collector Power Dissipation	350	mW
TJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C

Refer to 2N5551 for graphs

## Electrical Characteristics T<sub>a</sub>=25°C unless otherwise noted

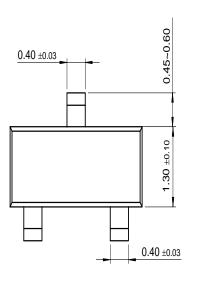
Symbol	Parameter	Test Condition	Min.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> =100μA, I <sub>E</sub> =0	180		V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> =1mA, I <sub>B</sub> =0	160		V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> =10μA, I <sub>C</sub> =0	6		V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> =120V, I <sub>E</sub> =0		50	nA
I <sub>EBO</sub>	Emitter Cut-off Current	V <sub>EB</sub> =4V, I <sub>C</sub> =0		50	nA
h <sub>FE</sub>	DC Current Gain	$V_{CE}=5V, I_{C}=1mA$ $V_{CE}=5V, I_{C}=10mA$ $V_{CE}=5V, I_{C}=50mA$	80 80 30	250	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_C$ =10mA, $I_B$ =1mA $I_C$ =50mA, $I_B$ =5mA		0.15 0.2	V V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	$I_C$ =10mA, $I_B$ =1mA $I_C$ =50mA, $I_B$ =5mA		1 1	V V
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> =10V, I <sub>C</sub> =10mA, f=100MHz	100	300	MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz		6	pF
NF	Noise Figure	$V_{CE}$ =5V, $I_{C}$ =250 $\mu$ A, $R_{S}$ =1 $K\Omega$ , $f$ =10Hz to 15.7 $K$ Mz		8	dB

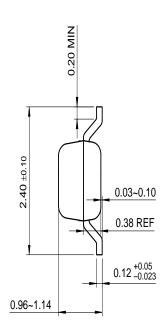
<sup>\*</sup> Pulse Test: Pulse Width=300µs, Duty Cycle=2%

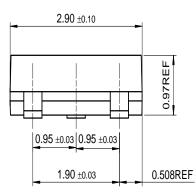


## **Package Dimensions**

## **SOT-23**







Dimensions in Millimeters

# Distributor of Fairchild Semiconductor: Excellent Integrated System Limited Datasheet of KST5551MTF - TRANS NPN 160V 0.6A SOT-23

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